## NSN 5962-01-356-9884

Memory Microcircuit - Page 1 of 2

Overall Length: 1.290 inches Overall Height:



View Online at https://aerobasegroup.com/nsn/5962-01-356-9884

Between 0.345 inches and 0.425 inches
Body Length:
1.290 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.150 inches and 0.210 inches
Maximum Power Dissipation Rating:
1.04 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
W/disable and monolithic and programmed and w/enable and 3-state output and high impedance
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
D-3 mil-m-38510
Current Rating Per Characteristic:
190.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
13.00 output picofarads
Time Rating Per Chacteristic:
100.00 nanoseconds access
Memory Device Type:
Prom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## NSN 5962-01-356-9884

Memory Microcircuit - Page 2 of 2



i ei ii ii iai Tybe And Quantity.	Tε	rminal	Type	And	Quantity:	
-----------------------------------	----	--------	------	-----	-----------	--

24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0